

## Dual Channel, Ultra-Low Resistance Load Switch

### General Description

The RTQ9740A is a small, ultra-low  $R_{ON}$ , dual channel load switch with EN controlled pin. The product contains two N-MOSFETs that can operate between an input voltage range of 0.8V to 5.5V. Also, it supports a maximum continuous current of 6A each channel. Each switch is independently controlled by EN pins (EN1 and EN2), which can directly interface with low-voltage control signals.

The RTQ9740A is available in the WDFN-14TL 3x2 package with exposed pad for high power and heat dissipation.

### Ordering Information

RTQ9740A □ □

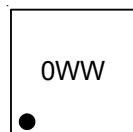
- Package Type  
QW : WDFN-14TL 3x2 (W-Type)
- Lead Plating System  
G : Green (Halogen Free and Pb Free)

Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

### Marking Information



0W : Product Code  
W : Date Code

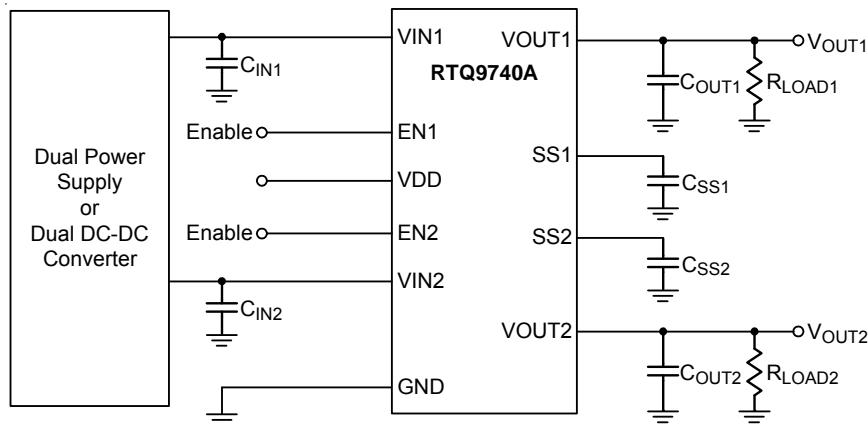
### Features

- Integrated Dual Channel Load Switch
- Input Voltage Range : 0.8V to 5.5V
- Ultra-Low  $R_{ON}$  Resistance
  - $R_{ON} = 22m\Omega$  at  $V_{IN} = 5V$  ( $V_{DD} = 5V$ )
  - $R_{ON} = 21m\Omega$  at  $V_{IN} = 3.3V$  ( $V_{DD} = 5V$ )
  - $R_{ON} = 21m\Omega$  at  $V_{IN} = 1.8V$  ( $V_{DD} = 5V$ )
- 6A Maximum Continuous Switch Current Per Channel
- Low Quiescent Current
  - 75 $\mu$ A (Both Channels)
  - 55 $\mu$ A (Single Channel)
- Low Control Input Threshold Enables Use of 1.4V/1.8V/2.5V/3.3V Logics
- Configurable Rise Time
- Quick Output Discharge (QOD)
- Adaptive Discharge Current
- 14T-Lead WDFN Package with Thermal Pad
- RoHS Compliant and Halogen Free

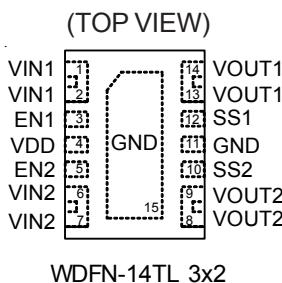
### Applications

- Ultrabook™
- Notebooks/Netbooks
- Tablet PC
- Consumer Electronics
- Set-Top Boxes/Residential Gateways
- Telecom Systems
- Solid State Drives (SSD)

### Simplified Application Circuit



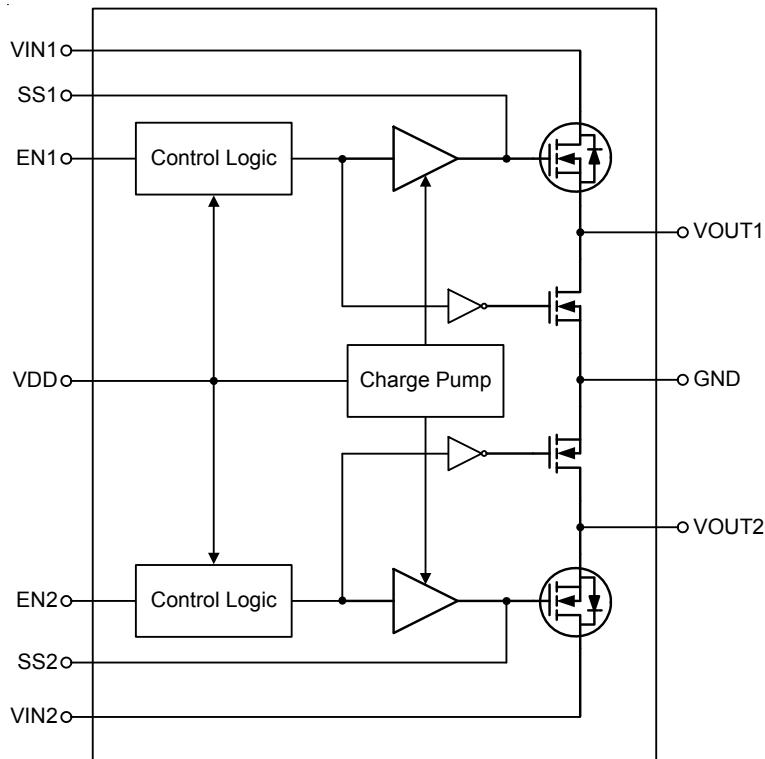
## Pin Configuration



## Functional Pin Description

Pin No.	Pin Name	Pin Function
1, 2	VIN1	Input voltage for switch 1. Bypass this input with a ceramic capacitor to GND. Recommended voltage range for this pin for optimal R <sub>ON</sub> performance is 0.8V to V <sub>DD</sub> .
3	EN1	Enable control input for switch 1 (Active High). Do not leave floating.
4	VDD	Charge pump voltage input. Power supply to the device. Recommended voltage range for this pin is 2.5V to 5.5V.
5	EN2	Enable control input for switch 2 (Active High). Do not leave floating.
6, 7	VIN2	Input voltage for switch 2. Bypass this input with a ceramic capacitor to GND. Recommended voltage range for this pin for optimal R <sub>ON</sub> performance is 0.8V to V <sub>DD</sub> .
8, 9	VOUT2	Switch 2 output.
10	SS2	Switch 2 slew rate control. Can be left floating.
11, 15 (Exposed Pad)	GND	Ground. The Exposed pad should be soldered to a large PCB and connected to GND for maximum thermal dissipation.
12	SS1	Switch 1 slew rate control. Can be left floating.
13, 14	VOUT1	Switch 1 output.

## Functional Block Diagram



## Operation

The RTQ9740A contains two N-MOSFETs which controlled by EN pin independently.

### Enable Control

Asserting  $\text{EN}_x$  pin high enables the switch. Switch will turn on as the EN signal is higher than  $V_{\text{ENH}}$ , and turn off when the EN signal is lower than  $V_{\text{ENL}}$ . Thus, it can operate under low voltage logic, please refer to the electrical characteristics. This pin cannot be left floating and must be tied either high or low voltage for proper functionality.

### Charge Pump

Provides sufficient bias voltage to both N-MOSFETs.

### Adjustable Rise Time

Connecting a capacitor to GND on the  $\text{SS}_x$  pin sets the slew rate for each channel. It could also be used to prevent in-rush current.

**Absolute Maximum Ratings** (Note 1)

- VIN1, VIN2, EN1, EN2, VDD, VOUT1, VOUT2, SS1, SS2 ----- -0.3V to 6V
- Maximum Continuous Switch Current Per Channel, IMAX ----- 6A
- Maximum Pulsed Switch Current, Pulse <300µs, 2% Duty Cycle Per Channel, IPLS ----- 8A
- Power Dissipation, PD @ TA = 25°C  
WDFN-14TL 3x2 ----- 2W
- Package Thermal Resistance (Note 2)  
WDFN-14TL 3x2, θJA ----- 50°C/W  
WDFN-14TL 3x2, θJC ----- 2°C/W
- Junction Temperature ----- 150°C
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Storage Temperature Range ----- -65°C to 150°C
- ESD Susceptibility (Note 3)  
HBM (Human Body Model) ----- 2kV  
CDM (Charged-Device Model) ----- 1kV

**Recommended Operating Conditions** (Note 4)

- VIN1,2, Input Voltage Range ----- 0.8V to V<sub>DD</sub>
- V<sub>DD</sub>, Charge Pump Voltage Input Range ----- 2.5V to 5.5V
- V<sub>EN1,2</sub>, EN Voltage Range ----- 0V to V<sub>DD</sub>
- Junction Temperature Range ----- -40°C to 125°C
- Ambient Temperature Range ----- -40°C to 105°C

**Electrical Characteristics**

(VIN = 0.8V to 5.5V, TA = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>EN Input Supply</b>						
Input Voltage	High-Level	V <sub>ENH</sub>	1.4	--	5.5	V
	Low-Level	V <sub>ENL</sub>	0	--	0.5	
ENx Pin Input Leakage Current	I <sub>EN</sub>	V <sub>EN</sub> = 5.5V	--	--	1	µA

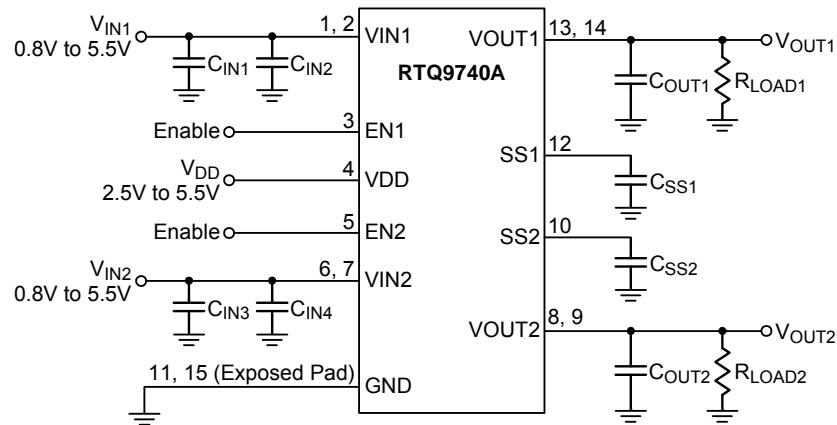
(V<sub>DD</sub> = 5V, VIN = 0.8V to V<sub>DD</sub>, TA = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Power Supplies and Currents</b>						
V <sub>DD</sub> Quiescent Current (Both Channels)	I <sub>IN(VDD, ON)</sub>	I <sub>OUT1</sub> = I <sub>OUT2</sub> = 0A	--	75	115	µA
		V <sub>IN1,2</sub> = V <sub>EN1,2</sub> = V <sub>DD</sub> = 5V				
V <sub>DD</sub> Quiescent Current (Single Channel)	I <sub>IN(VDD, ON)</sub>	I <sub>OUT1</sub> = I <sub>OUT2</sub> = 0A	--	55	--	µA
		V <sub>IN1,2</sub> = V <sub>EN1</sub> = V <sub>DD</sub> = 5V, V <sub>EN2</sub> = GND				
V <sub>DD</sub> Shutdown Current	I <sub>IN(VDD, OFF)</sub>	V <sub>EN1,2</sub> = GND, V <sub>OUT1,2</sub> = 0V	--	--	2	µA

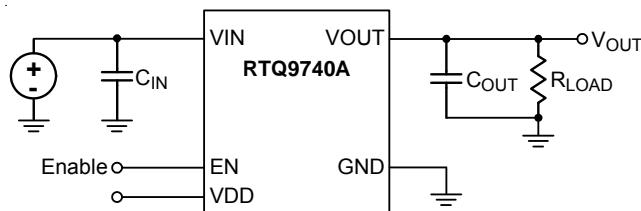
Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
VIN <sub>1,2</sub> Off-State Supply Current (Per Channel)	I <sub>IN(VIN, OFF)</sub>	V <sub>EN1,2</sub> = GND, V <sub>OUT1,2</sub> = 0V	V <sub>IN1,2</sub> = 5V	--	--	8	μA
			V <sub>IN1,2</sub> = 3.3V	--	--	3	
			V <sub>IN1,2</sub> = 1.8V	--	--	2	
			V <sub>IN1,2</sub> = 0.8V	--	--	1	
<b>Resistance Characteristics</b>							
ON-State Resistance	R <sub>ON</sub>	I <sub>OUT</sub> = -200mA, V <sub>DD</sub> = 5V	V <sub>IN</sub>	T <sub>A</sub>	Min	Typ	Max
			5V	25°C	--	22	25
				-40°C to 85°C	--	--	28
				-40°C to 105°C	--	--	31
			3.3V	25°C	--	21	24
				-40°C to 85°C	--	--	27
				-40°C to 105°C	--	--	29
			1.8V	25°C	--	21	24
				-40°C to 85°C	--	--	27
				-40°C to 105°C	--	--	29
			1.5V	25°C	--	21	24
				-40°C to 85°C	--	--	27
				-40°C to 105°C	--	--	29
			1.2V	25°C	--	21	24
				-40°C to 85°C	--	--	27
				-40°C to 105°C	--	--	29
			0.8V	25°C	--	21	24
				-40°C to 85°C	--	--	27
				-40°C to 105°C	--	--	29
Output Pull-Down Resistance	R <sub>PD</sub>	V <sub>EN</sub> = 0V, V <sub>IN</sub> = 5V, I <sub>OUT</sub> = 15mA		--	220	300	Ω



## Typical Application Circuit



## Timing Diagram



Single Channel Shown for Clarity

TEST CIRCUIT

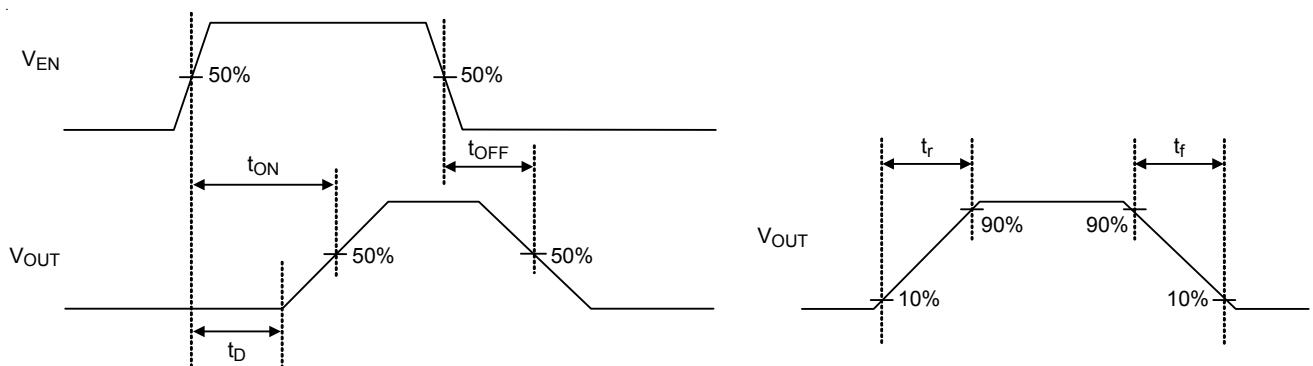


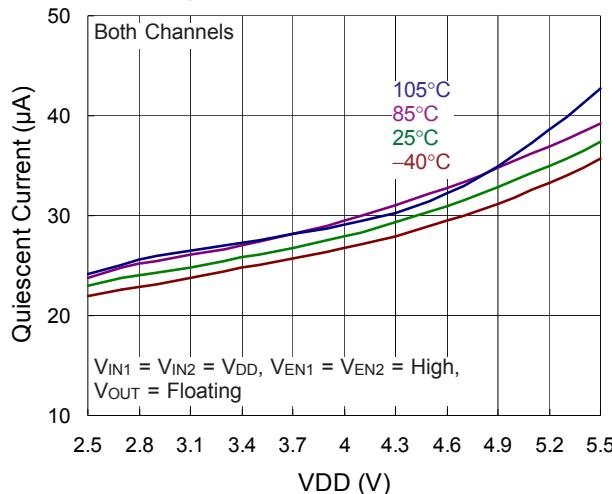
Figure 1. Test Circuit and  $t_{ON}/t_{OFF}$  Waveforms

**Timing Characteristics**

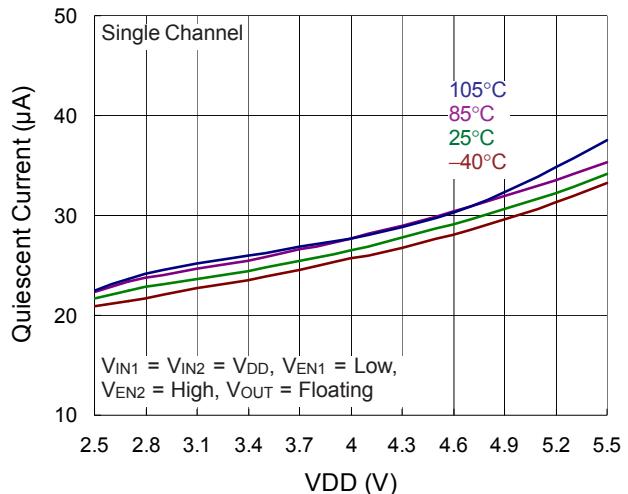
Parameter		Test Conditions	Min	Typ	Max	Unit
$V_{IN} = EN = V_{DD} = 5V, T_A = 25^\circ C$						
ton	Turn-On Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	1220	--	$\mu s$
toff	Turn-Off Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	4	--	
tR	VOUT Rise Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	1350	--	
tF	VOUT Fall Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	3	--	
tD	ON Delay Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	400	--	
$V_{IN} = 0.8V, EN = V_{DD} = 5V, T_A = 25^\circ C$						
ton	Turn-On Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	580	--	$\mu s$
toff	Turn-Off Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	80	--	
tR	VOUT Rise Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	280	--	
tF	VOUT Fall Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	20	--	
tD	ON Delay Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	400	--	
$V_{IN} = EN = V_{DD} = 3.3V, T_A = 25^\circ C$						
ton	Turn-On Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	960	--	$\mu s$
toff	Turn-Off Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	6	--	
tR	VOUT Rise Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	940	--	
tF	VOUT Fall Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	3	--	
tD	ON Delay Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	400	--	
$V_{IN} = 0.8V, EN = V_{DD} = 3.3V, T_A = 25^\circ C$						
ton	Turn-On Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	560	--	$\mu s$
toff	Turn-Off Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	175	--	
tR	VOUT Rise Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	280	--	
tF	VOUT Fall Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	40	--	
tD	ON Delay Time	$R_{LOAD} = 10\Omega, C_{OUT} = 0.1\mu F, C_{SS} = 1000pF$	--	400	--	

## Typical Operating Characteristics

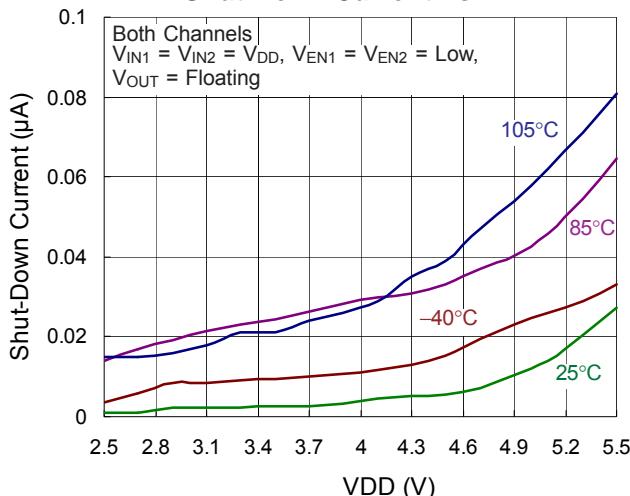
**Quiescent Current vs. VDD**



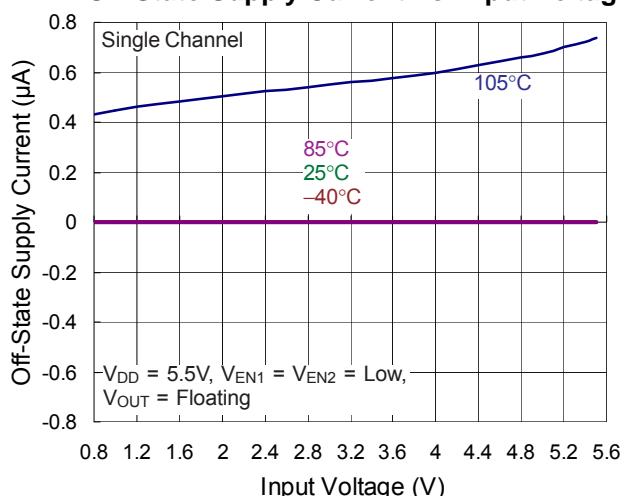
**Quiescent Current vs. VDD**



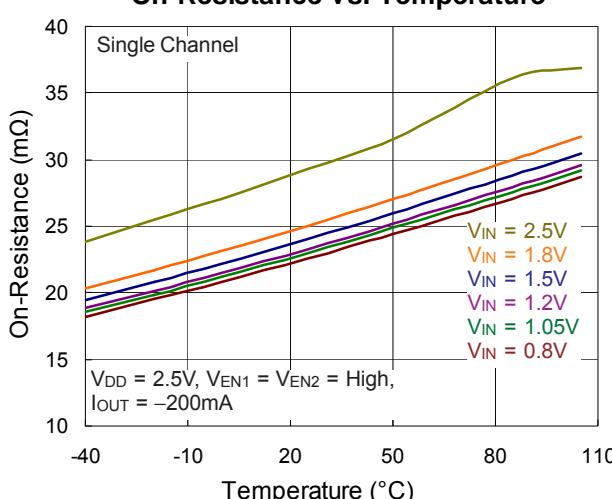
**Shut-Down Current vs. VDD**



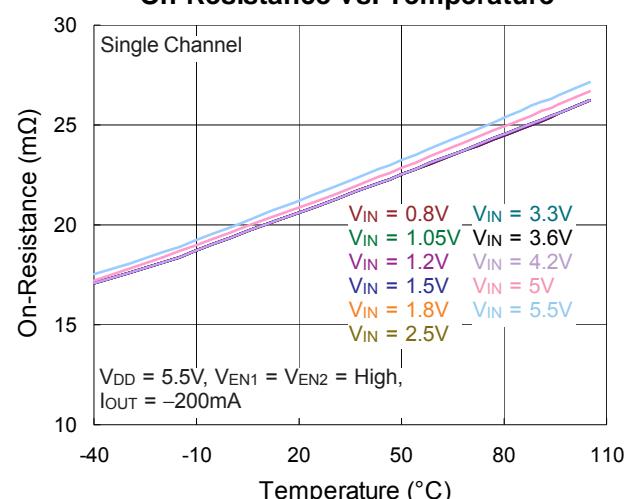
**Off-State Supply Current vs. Input Voltage**

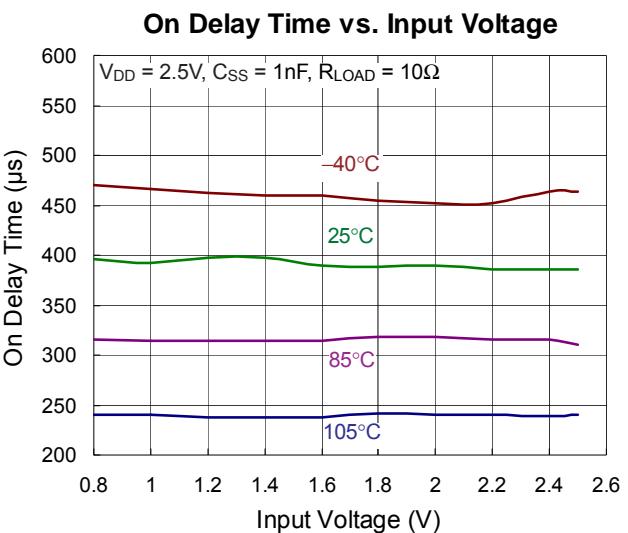
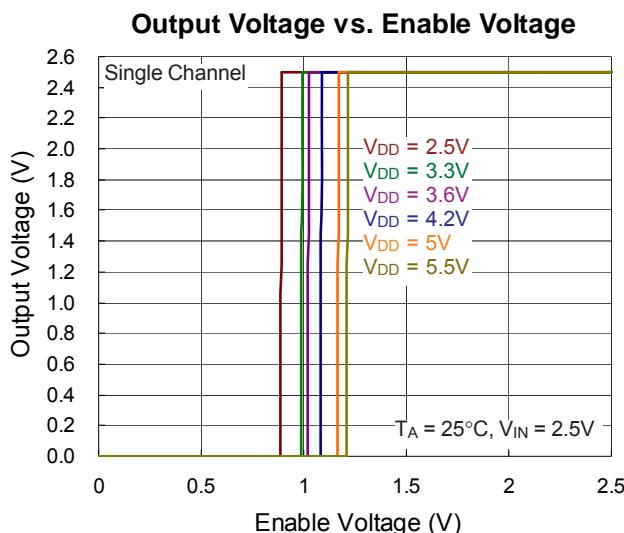
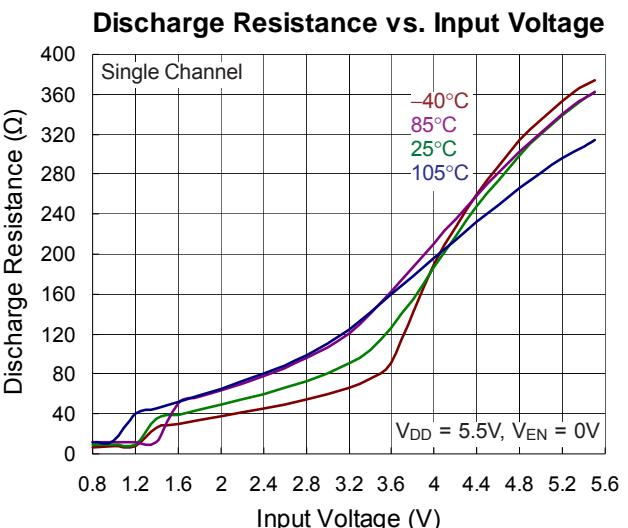
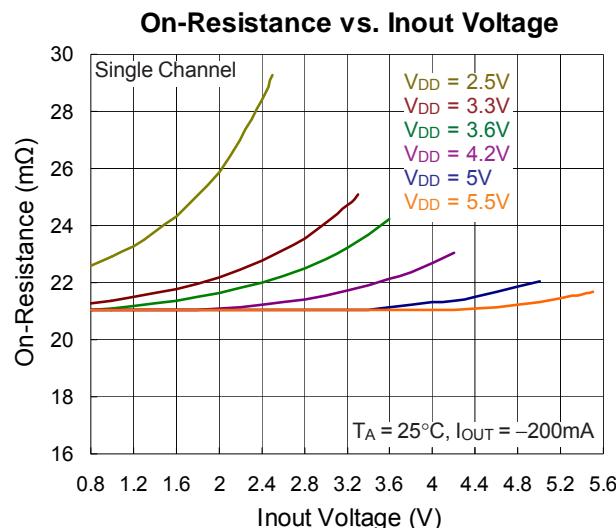
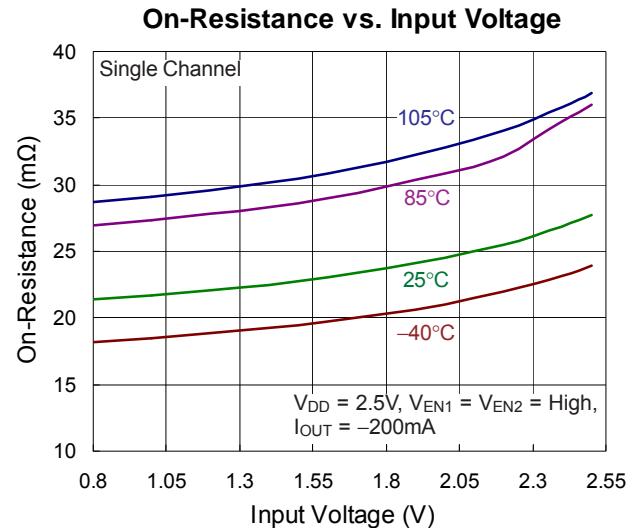
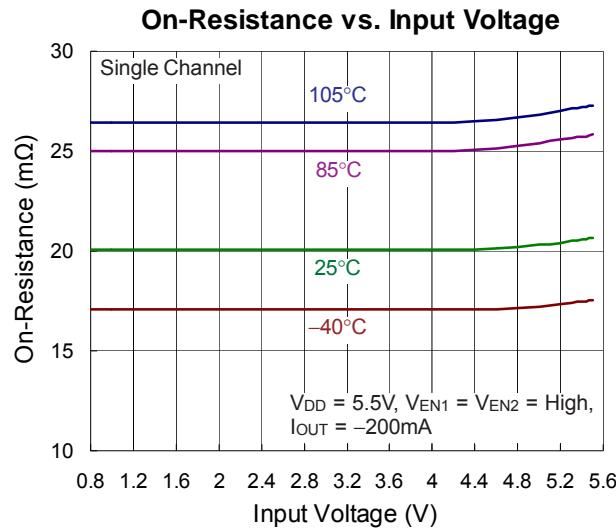


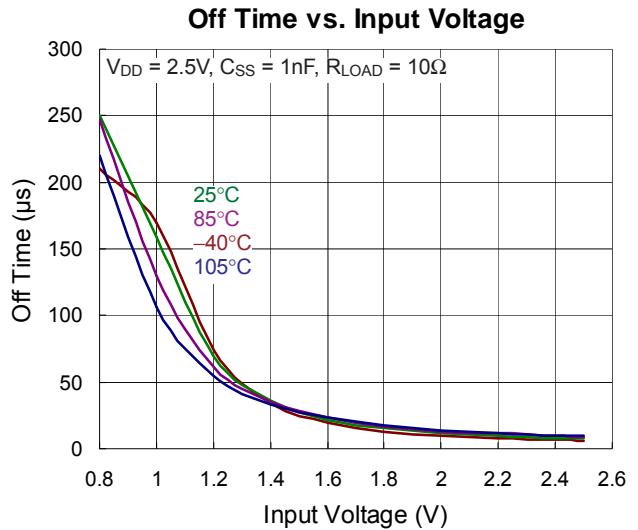
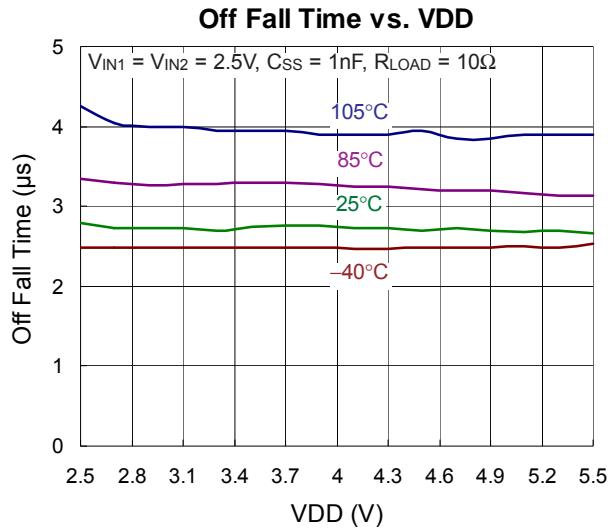
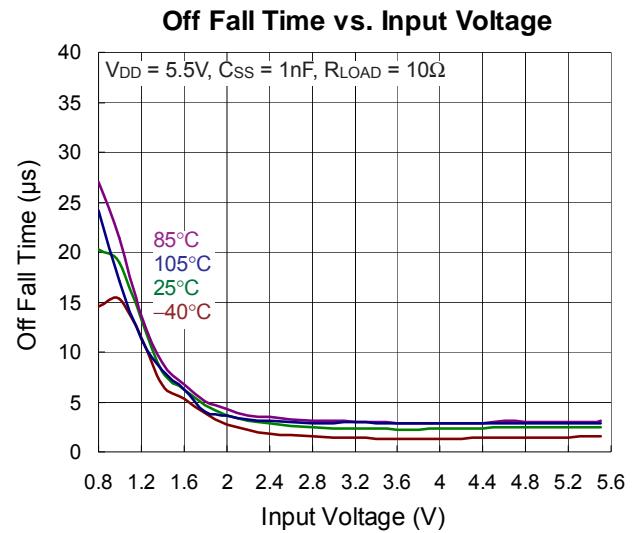
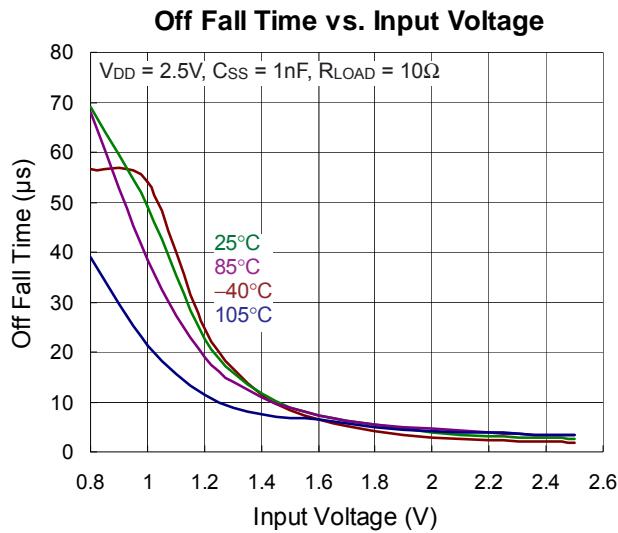
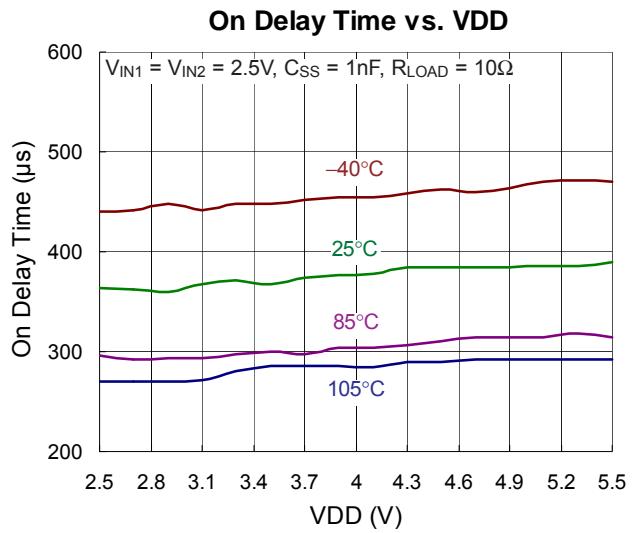
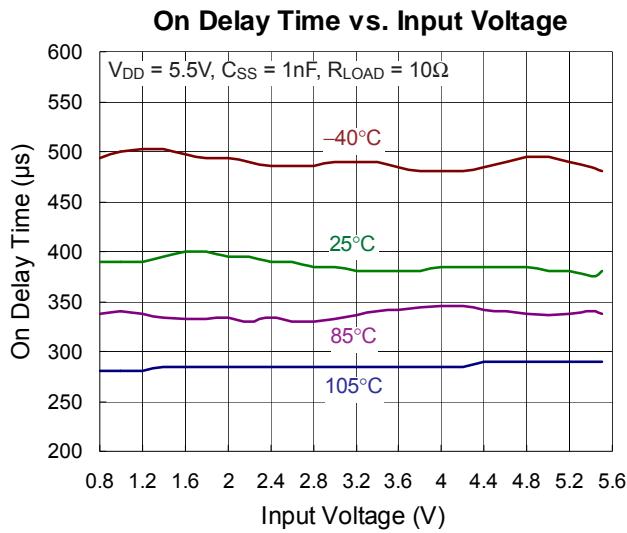
**On-Resistance vs. Temperature**

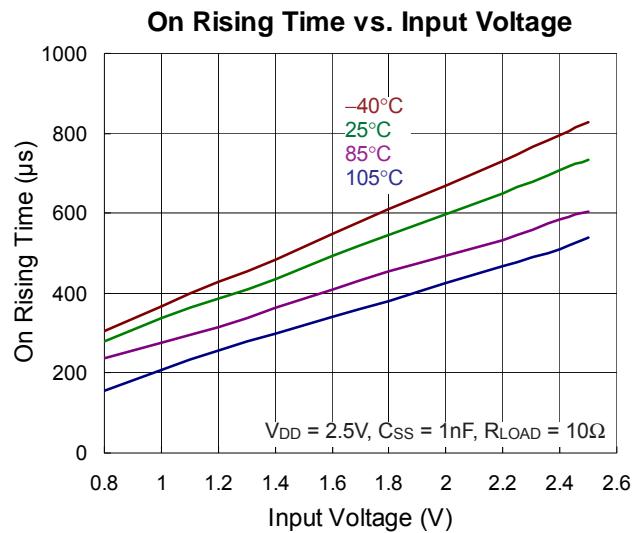
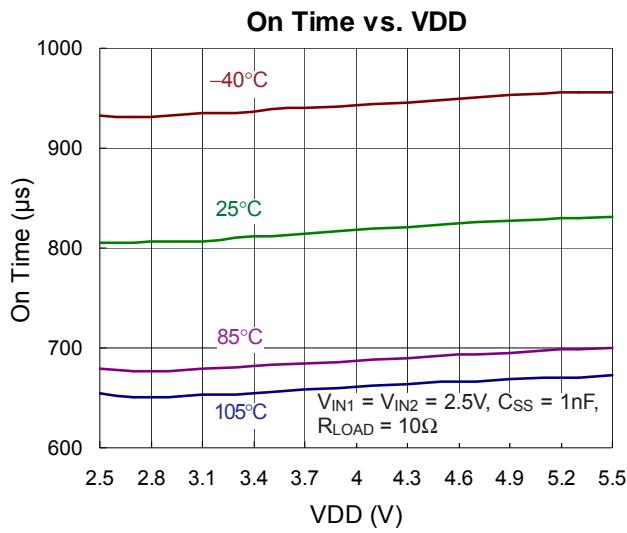
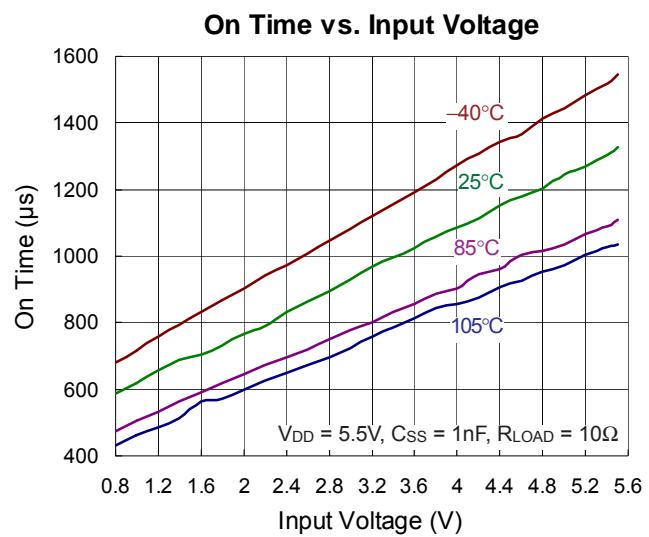
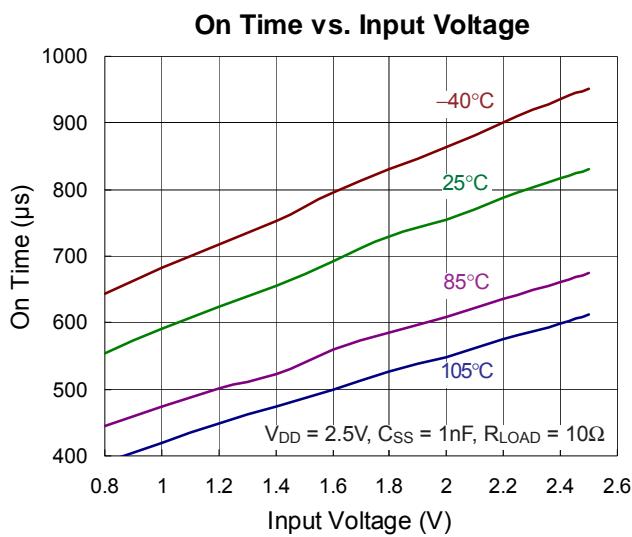
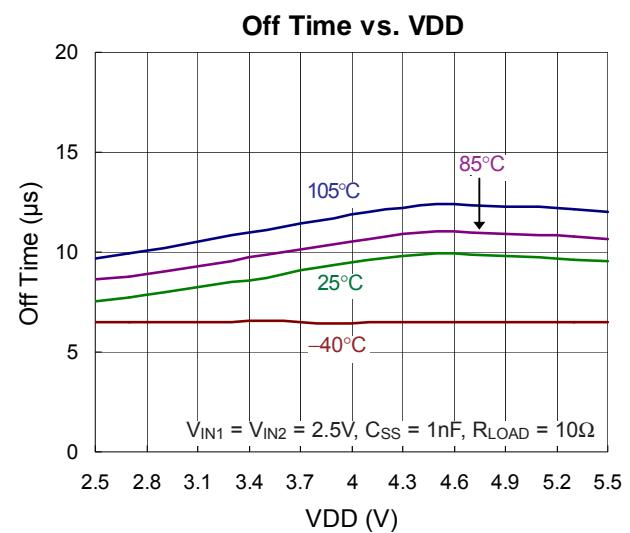
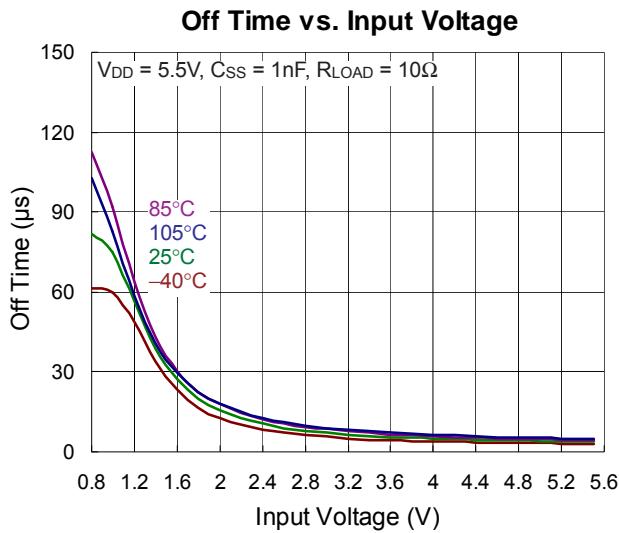


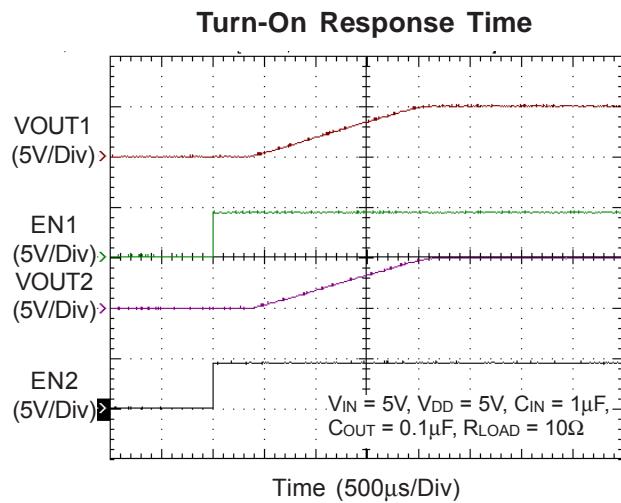
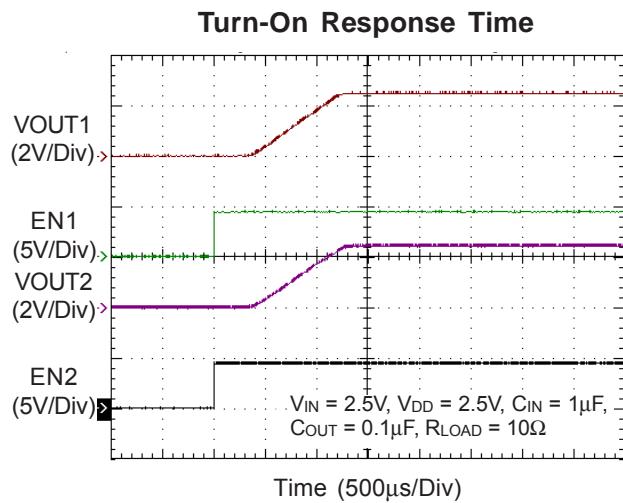
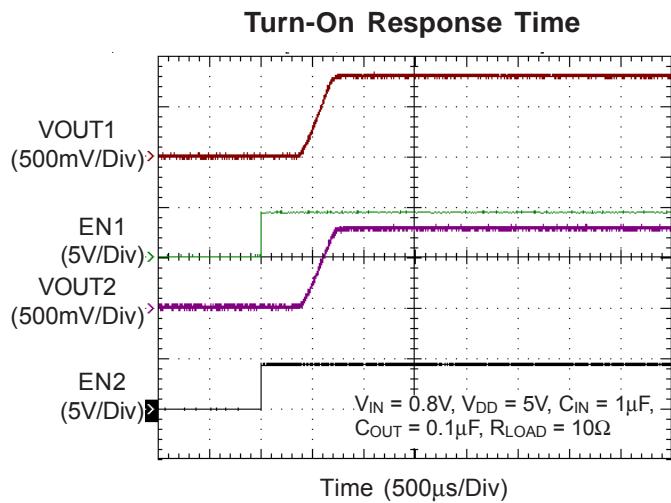
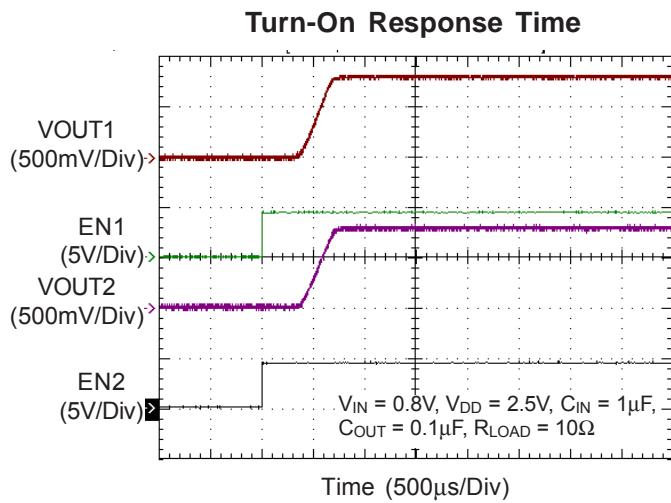
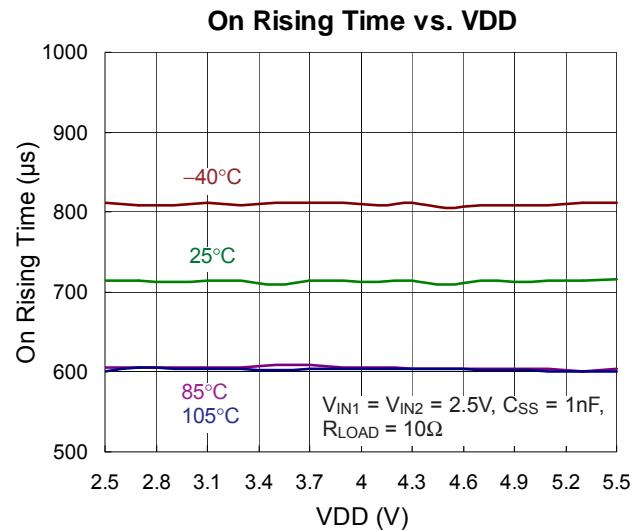
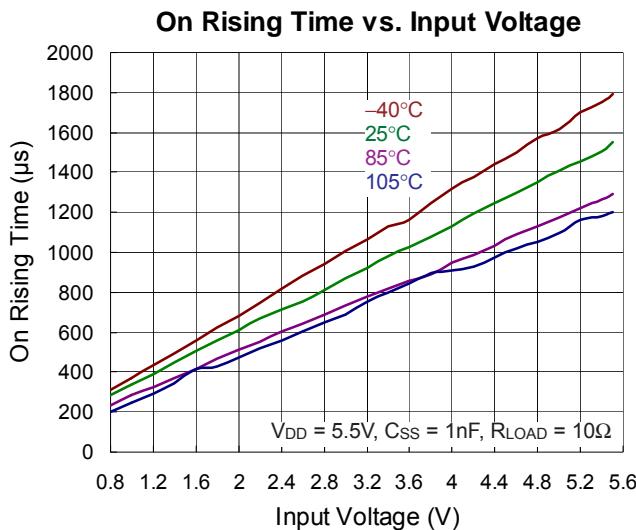
**On-Resistance vs. Temperature**



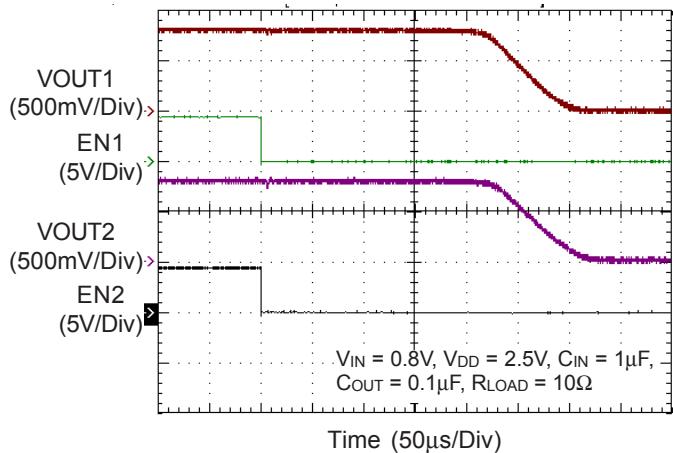




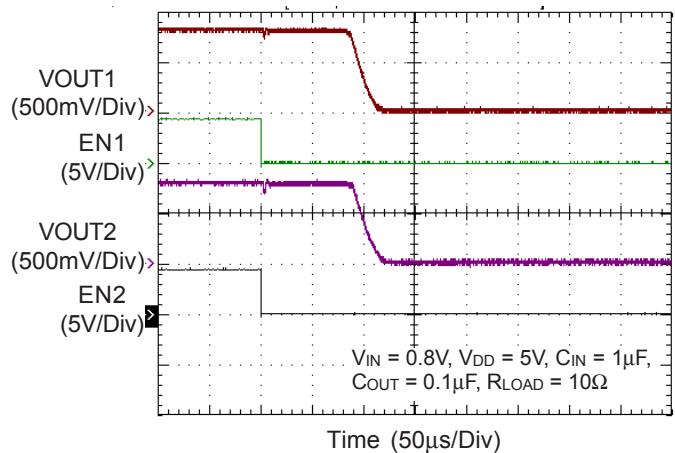




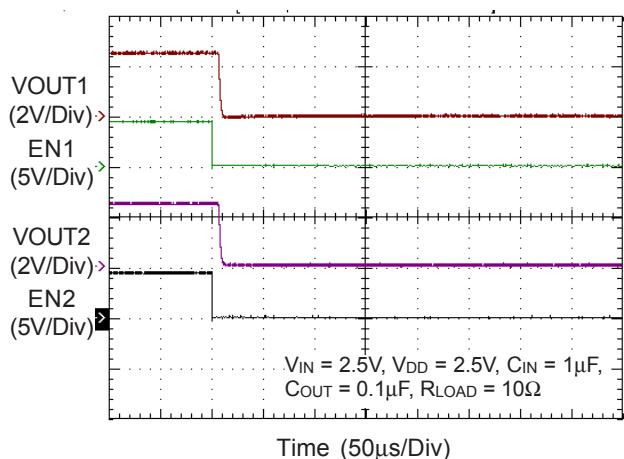
### Turn-Off Response Time



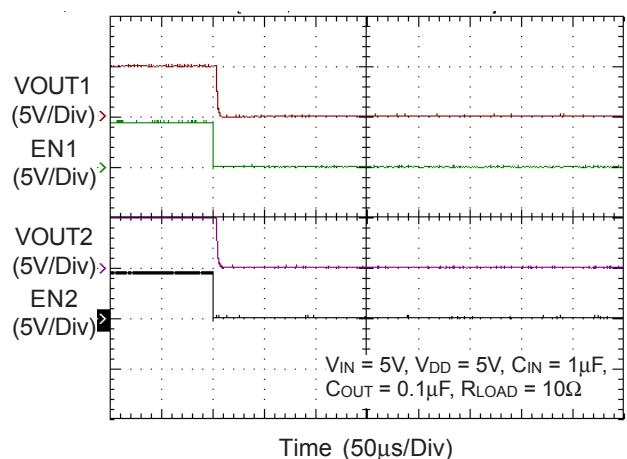
### Turn-Off Response Time



### Turn-Off Response Time



### Turn-Off Response Time



## Application Information

The RTQ9740A is a small, ultra-low  $R_{ON}$ , dual channel load switch with EN controlled pins, and is equipped with a charge pump circuitry to drive the internal N-MOSFET switch. The product contains two N-channel MOSFETs that can operate between input voltage range of 0.8V to 5.5V. It also supports a maximum continuous current of 6A each channel and a maximum pulsed switch current of 8A (pulse <300μs). Each switch is independently controlled by EN pins (EN1 and EN2), which can directly interface with low-voltage control signals.

### Input and Output

$V_{INx}$  (input) is the power source connection to the internal circuitry and the Drain of the MOSFET.  $V_{OUTx}$  (output) is the Source of the MOSFET. In a typical application, current flows through the switch from  $V_{INx}$  to  $V_{OUTx}$  toward the load. If  $V_{OUTx}$  is greater than  $V_{INx}$ , current will flow from  $V_{OUTx}$  to  $V_{INx}$  since the MOSFET is bidirectional when on.

### Chip Enable Input

The switch will be disabled when the  $EN_x$  pin is in a logic low condition. During this condition, the internal circuitry and MOSFET will be turned off, reducing the supply current to 0.1μA typical. Floating the  $EN_x$  may cause unpredictable operation.  $EN_x$  should not be allowed to go negative with respect to GND.

### Supply Filter/Bypass Capacitor

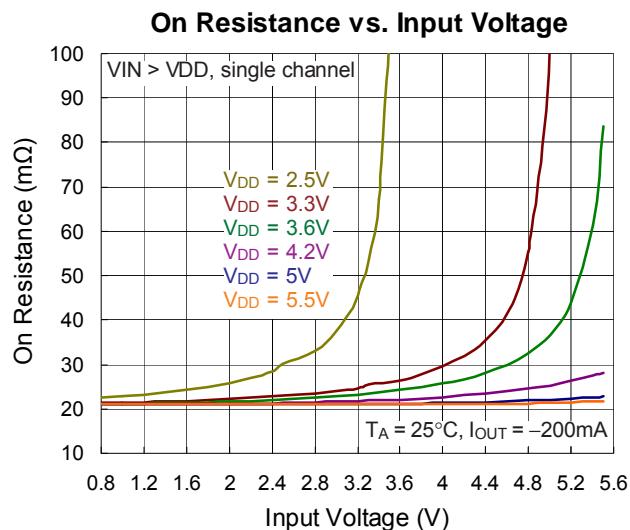
A 1μF or greater low-ESR ceramic capacitor from  $V_{IN}$  to GND, located at the device is strongly recommended to prevent the input voltage drooping during high current application. However, higher capacitor values will further reduce the voltage droop on the input. Furthermore, without the bypass capacitor, an output short may cause sufficient ringing on the input (from source lead inductance) to destroy the internal control circuitry. The input transient must not exceed 6V of the absolute maximum supply voltage even for a short duration.

### Output Filter Capacitor

A 10 to 1 ratio of supply capacitor to output capacitor from  $V_{OUTx}$  to GND is recommended to prevent the in-rush currents during low supply voltage start-up. Because the integrated body diode in the load switch, higher output capacitor can cause output voltage to exceed supply voltage when the system supply is removed. A output capacitor smaller then supply capacitor is recommended to prevent the current flow through the integrated body diode from output to system supply.

### Charge Pump

The switch has an internal charge pump circuit that is supplied from  $V_{DD}$  pin to afford sufficient bias voltage to both N-channel MOSFETs. The recommended  $V_{DD}$  voltage range is 2.5V to 5.5V, and must above  $V_{IN}$  for optimal ultra-low  $R_{ON}$  performance, or the value of  $R_{ON}$  will be greater than the value listed in the ELECTRICAL CHARACTERISTICS table.



### Adjustable Rise Time

The RTQ9740A provides an external adjustable rise time function. The adjustable rise time is used to prevent large inrush current and output voltage overshoot while the switch is being powered-up. The external capacitor connected from SS pins to GND is charged by a 1μA current source to set each rise time.

## Discharge Operation

When ENx is low, the RTQ9740A will discharge the system residual voltage using internal MOSFET connected between the VOUTx and GND. The discharge current depends on the voltage at the VOUTx pin. When the voltage at the VOUTx is lower than 0.8V, the RTQ9740A will fully turn the internal MOSFET on to pull the VOUTx low.

## Thermal Considerations

The junction temperature should never exceed the absolute maximum junction temperature  $T_{J(MAX)}$ , listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance,  $\theta_{JA}$ , is highly package dependent. For a WDFN-14TL 3x2 package, the thermal resistance,  $\theta_{JA}$ , is 50°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. The maximum power dissipation at  $T_A = 25^\circ\text{C}$  can be calculated as below :

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (50^\circ\text{C}/\text{W}) = 2\text{W} \text{ for a WDFN-14TL 3x2 package.}$$

The maximum power dissipation depends on the operating ambient temperature for the fixed  $T_{J(MAX)}$  and the thermal resistance,  $\theta_{JA}$ . The derating curves in Figure 2 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

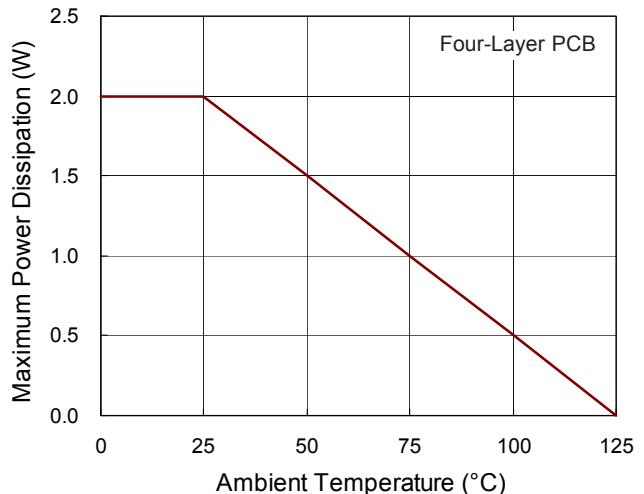
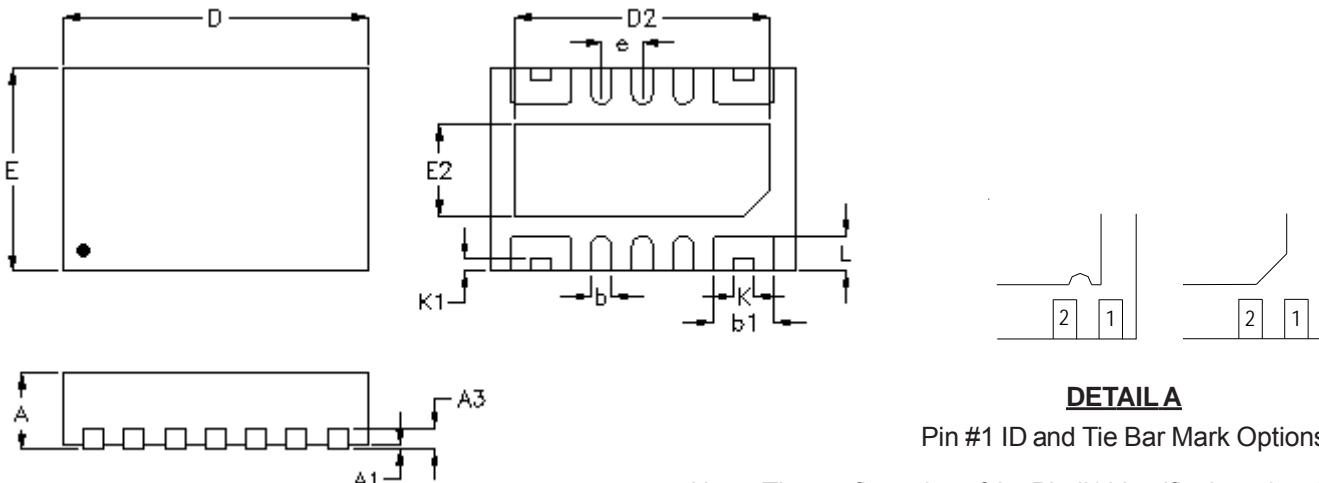


Figure 2. Derating Curve of Maximum Power Dissipation

## Outline Dimension



### DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.150	0.250	0.006	0.010
b1	0.550	0.650	0.022	0.026
D	2.900	3.100	0.114	0.122
D2	2.450	2.550	0.096	0.100
E	1.900	2.100	0.075	0.083
E2	0.850	0.950	0.033	0.037
e	0.400		0.016	
K	0.200		0.008	
K1	0.120		0.005	
L	0.300	0.400	0.012	0.016

## W-Type 14TL DFN 3x2 Package

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